TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type

# SSM3K15CT

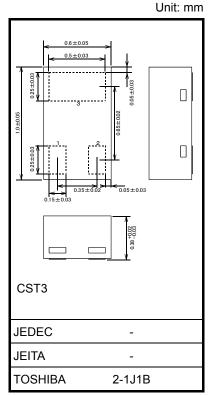
# High-Speed Switching Applications Analog Switch Applications

- Optimum for high-density mounting in small packages
- Low ON-resistance
  - :  $R_{on} = 4.0 \Omega \text{ (max) } (@V_{GS} = 4 \text{ V})$
  - :  $R_{on} = 7.0 \Omega \text{ (max) } (@V_{GS} = 2.5 \text{ V})$

## Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		$V_{DS}$	30	V	
Gate-source voltage		$V_{GSS}$	±20	V	
Drain current	DC	ΙD	100	mA	
	Pulse	I <sub>DP</sub>	200		
Drain power dissipation (Ta = 25°C)		P <sub>D</sub> (Note 1)	100	mW	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature		T <sub>stg</sub>	-55~150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



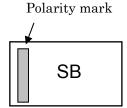
Weight: 0.75 mg (typ.)

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on an FR4 board

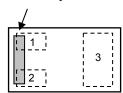
 $(10 \text{ mm} \times 10 \text{ mm} \times 1.0 \text{ t}, \text{ Cu Pad: } 100 \text{ mm}^2)$ 

### Marking (Top View)



### **Pin Condition (Top View)**

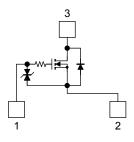
Polarity mark (on the top)



- 1. Gate
- 2. Source
- 3. Drain

\*Electrodes: On the bottom

### **Equivalent Circuit**



## **Handling Precaution**

When handling individual devices that are not yet mounted on a circuit board, ensure that the environment is protected against electrostatic discharge. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

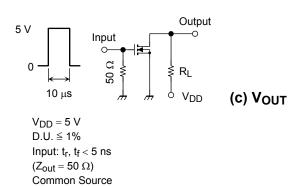
## **Electrical Characteristics (Ta = 25°C)**

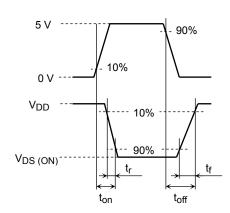
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$	_	_	±1	μА
Drain-source brea	kdown voltage	V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0$	30	_	_	V
Drain cut-off curre	nt	I <sub>DSS</sub>	$V_{DS} = 30 \text{ V}, V_{GS} = 0$	_	_	1	μА
Gate threshold vol	tage	V <sub>th</sub>	V <sub>DS</sub> = 3 V, I <sub>D</sub> = 0.1 mA	0.8	_	1.5	V
Forward transfer a	dmittance	Y <sub>fs</sub>	V <sub>DS</sub> = 3 V, I <sub>D</sub> = 10 mA	25	_	_	mS
Drain-Source ON-resistance		R <sub>DS (ON)</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 4 V	_	2.2	4.0	Ω
			$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$	_	4.0	7.0	
Input capacitance		C <sub>iss</sub>	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	7.8	_	pF
Reverse transfer of	apacitance	C <sub>rss</sub>	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	3.6	_	pF
Output capacitance		Coss	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	8.8	_	pF
Switching time	Turn-on time	t <sub>on</sub>	V <sub>DD</sub> = 5 V, I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0~5 V	_	50	_	- ns
	Turn-off time	t <sub>off</sub>			180		

## **Switching Time Test Circuit**







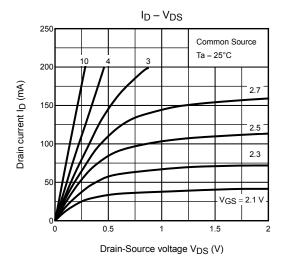


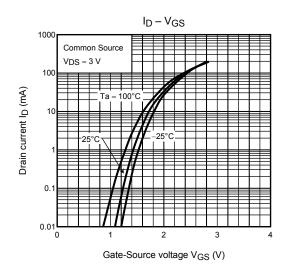
#### **Precaution**

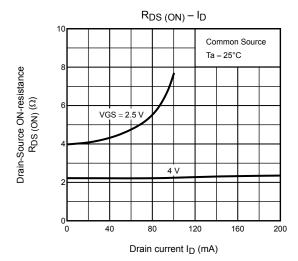
 $V_{th}$  can be expressed as the voltage between gate and source when the low operating current value is  $I_D$  = 100  $\mu$ A for this product. For normal switching operation,  $V_{GS\ (on)}$  requires a higher voltage than  $V_{th}$  and  $V_{GS\ (off)}$  requires a lower voltage than  $V_{th}$ . (The relationship can be established as follows:  $V_{GS\ (off)} < V_{th} < V_{GS\ (on)}$ .)

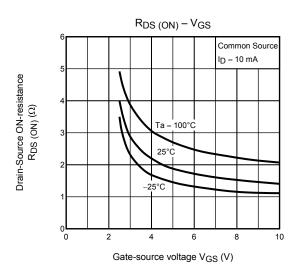
Take this into consideration when using the device.

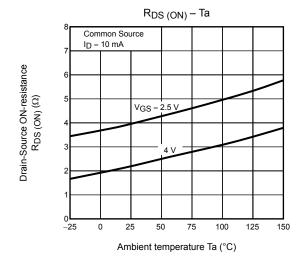
Ta = 25°C

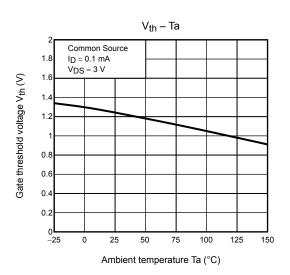




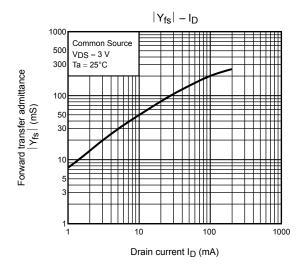


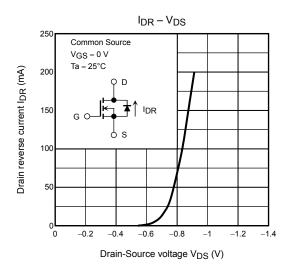


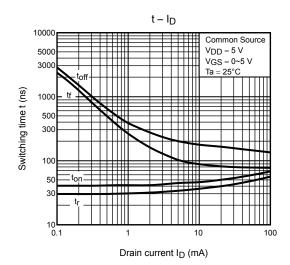


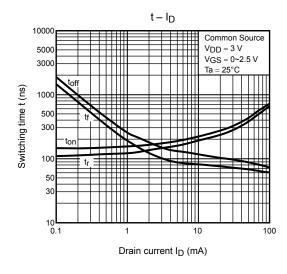


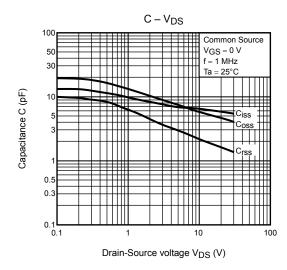
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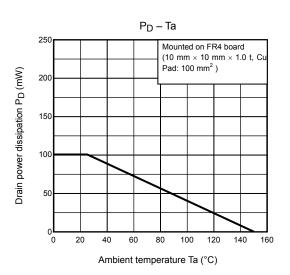












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20070701-EN GENERAL

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